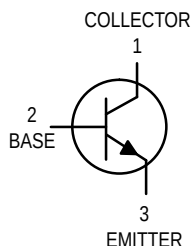


Amplifier Transistors

NPN Silicon

BC237,A,B,C
BC238B,C
BC239,C



MAXIMUM RATINGS

Rating	Symbol	BC 237	BC 238	BC 239	Unit
Collector–Emitter Voltage	V_{CEO}	45	25	25	Vdc
Collector–Emitter Voltage	V_{CES}	50	30	30	Vdc
Emitter–Base Voltage	V_{EBO}	6.0	5.0	5.0	Vdc
Collector Current — Continuous	I_C	100			mA dc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8			mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.0 8.0			Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150			$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	$^\circ\text{C/W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	125	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = 2.0\text{ mA}$, $I_B = 0$)	BC237 BC238 BC239	$V_{(BR)CEO}$	45 25 25	— — —	— — —	V
Emitter–Base Breakdown Voltage ($I_E = 100\text{ }\mu\text{A}$, $I_C = 0$)	BC237 BC238 BC239	$V_{(BR)EBO}$	6.0 5.0 5.0	— — —	— — —	V
Collector Cutoff Current ($V_{CE} = 30\text{ V}$, $V_{BE} = 0$)	BC238 BC239	I_{CES}	— —	0.2 0.2	15 15	nA
($V_{CE} = 50\text{ V}$, $V_{BE} = 0$)	BC237		—	0.2	15	
($V_{CE} = 30\text{ V}$, $V_{BE} = 0$) $T_A = 125^\circ\text{C}$	BC238 BC239		— —	0.2 0.2	4.0 4.0	μA
($V_{CE} = 50\text{ V}$, $V_{BE} = 0$) $T_A = 125^\circ\text{C}$	BC237		—	0.2	4.0	



BC237,A,B,C BC238B,C BC239,C**ELECTRICAL CHARACTERISTICS** ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Typ	Max	Unit			
ON CHARACTERISTICS									
DC Current Gain (I _C = 10 μA, V _{CE} = 5.0 V) (I _C = 2.0 mA, V _{CE} = 5.0 V) (I _C = 100 mA, V _{CE} = 5.0 V)	BC237A	h _{FE}	—	90	—	—			
	BC237B/238B		—	150	—				
	BC237C/238C/239C		—	270	—				
	BC237		120	—	800				
	BC239		120	—	800				
	BC237A		120	170	220				
	BC237B/238B		200	290	460				
	BC237C/238C/239C		380	500	800				
	BC237A		—	120	—				
	BC237B/238B		—	180	—				
	BC237C/238C/239C		—	300	—				
	Collector–Emitter On Voltage (I _C = 10 mA, I _B = 0.5 mA) (I _C = 100 mA, I _B = 5.0 mA)		BC237/BC238/BC239	V _{CE(sat)}	—		0.07	0.2	V
			BC237/BC239		—		0.2	0.6	
			BC238		—		—	0.8	
	Base–Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.5 mA) (I _C = 100 mA, I _B = 5.0 mA)			V _{BE(sat)}	—		0.6	0.83	V
		—	—		1.05				
Base–Emitter On Voltage (I _C = 100 μA, V _{CE} = 5.0 V) (I _C = 2.0 mA, V _{CE} = 5.0 V) (I _C = 100 mA, V _{CE} = 5.0 V)		V _{BE(on)}	—	0.5	—	V			
			0.55	0.62	0.7				
			—	0.83	—				
DYNAMIC CHARACTERISTICS									
Current–Gain — Bandwidth Product (I _C = 0.5 mA, V _{CE} = 3.0 V, f = 100 MHz) (I _C = 10 mA, V _{CE} = 5.0 V, f = 100 MHz)	BC237	f _T	—	100	—	MHz			
	BC238		—	120	—				
	BC239		—	140	—				
	BC237		150	200	—				
	BC238		150	240	—				
	BC239		150	280	—				
Collector–Base Capacitance (V _{CB} = 10 V, I _C = 0, f = 1.0 MHz)		C _{obo}	—	—	4.5	pF			
Emitter–Base Capacitance (V _{EB} = 0.5 V, I _C = 0, f = 1.0 MHz)		C _{ibo}	—	8.0	—	pF			
Noise Figure (I _C = 0.2 mA, V _{CE} = 5.0 V, R _S = 2.0 kΩ, f = 1.0 kHz) (I _C = 0.2 mA, V _{CE} = 5.0 V, R _S = 2.0 kΩ, f = 1.0 kHz, Δf = 200 Hz)	BC239	NF	—	2.0	4.0	dB			
	BC237		—	2.0	10				
	BC238		—	2.0	10				
	BC239		—	2.0	4.0				

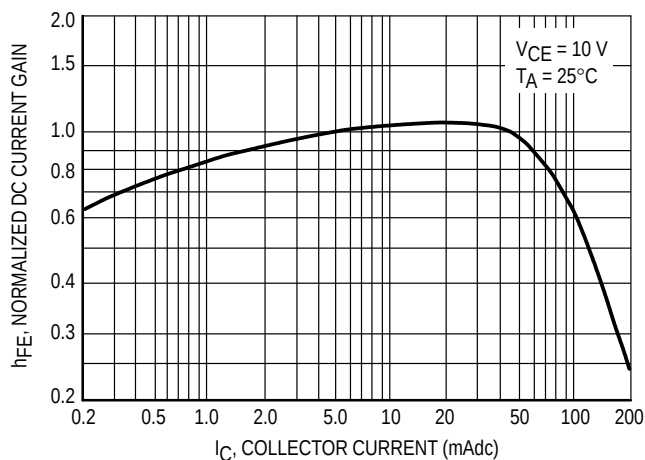


Figure 1. Normalized DC Current Gain

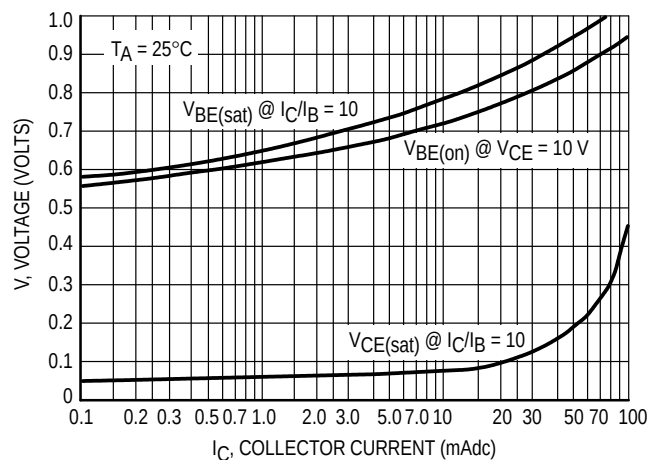


Figure 2. "Saturation" and "On" Voltages

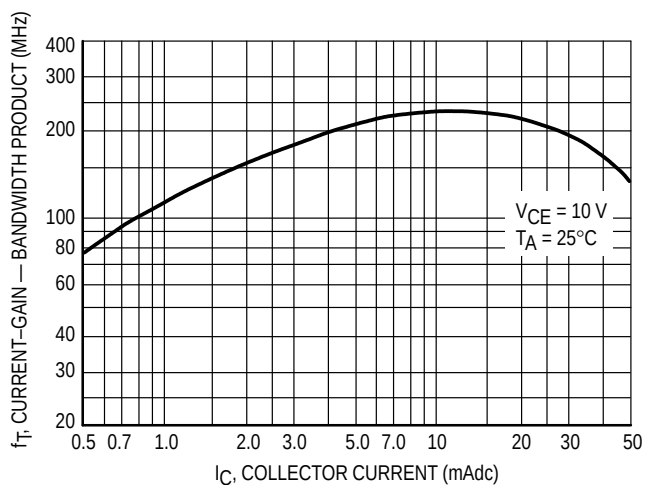


Figure 3. Current-Gain — Bandwidth Product

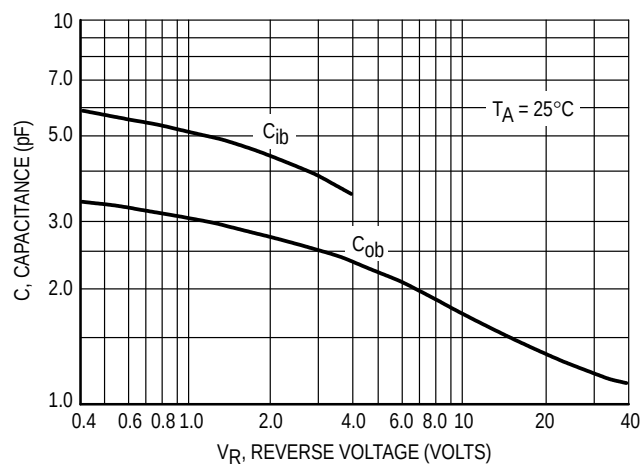


Figure 4. Capacitances

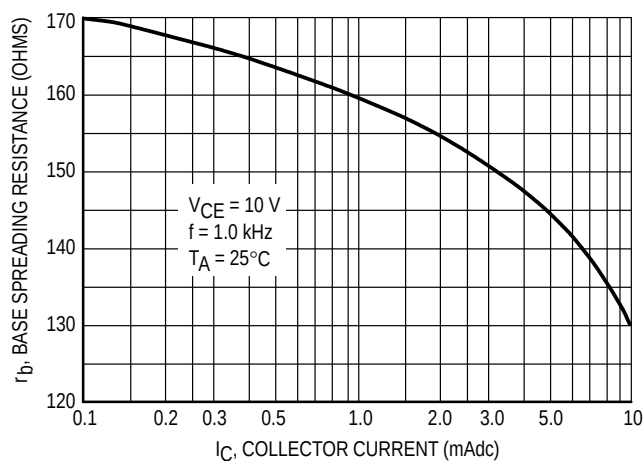
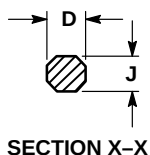
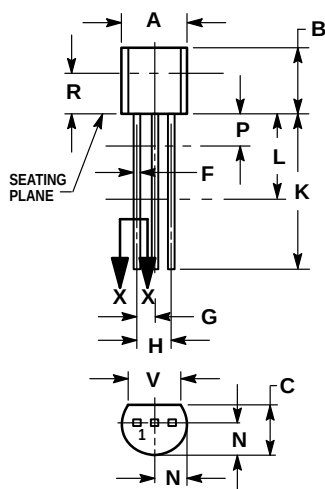


Figure 5. Base Spreading Resistance

PACKAGE DIMENSIONS



SECTION X-X

**CASE 029-04
(TO-226AA)
ISSUE AD**

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K. MINIMUM LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

STYLE 17:

1. COLLECTOR
2. BASE
3. EMITTER

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How to reach us:

USA/EUROPE: Motorola Literature Distribution;
P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki,
6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE (602) 244-6609
INTERNET: http://Design-NET.com

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,
51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

